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General Description:

Gallium arsenide infrared emitting diode coupled with a silicon darlington phototransistor; minus 55 degrees c to plus 100 degrees c operating temperature range; 0.350 in. Lg; 0.373 in. H; 0.280 in. W

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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